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Inclosure Material:

Ceramic and metal

Overall Length:

0.235 inches

Overall Diameter:

0.300 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter reverse voltage, with base short-circuited to emitter and 33.0 collector to emitter voltage/static/base open and 4.0

emitter to base voltage, static, collector open

Current Rating Per Characteristic:

1.00 amperes source cutoff current

Power Rating Per Characteristic:

18.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

80063-sm-b-745775 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unc

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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